



MBR3045C

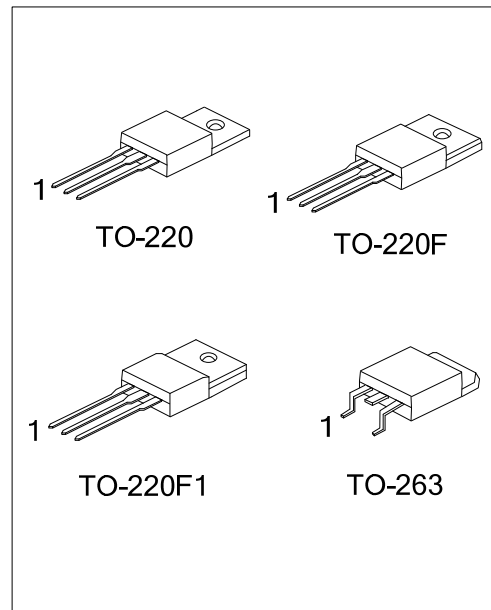
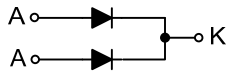
DIODE

30A SCHOTTKY BARRIER RECTIFIER DIODES

FEATURES

- * Guard Ring for Transient Protection
- * Low Power Loss, High Efficiency
- * High Surge Capability
- * High Current Capability and Low Forward Voltage Drop

SYMBOL



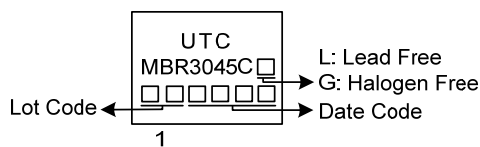
ORDERING INFORMATION

Order Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
MBR3045CL-TA3-T	MBR3045CG-TA3-T	TO-220	A	K	A	Tube
MBR3045CL-TF1-T	MBR3045CG-TF1-T	TO-220F1	A	K	A	Tube
MBR3045CL-TF3-T	MBR3045CG-TF3-T	TO-220F	A	K	A	Tube
MBR3045CL-TQ2-T	MBR3045CG-TQ2-T	TO-263	A	K	A	Tube
MBR3045CL-TQ2-R	MBR3045CG-TQ2-R	TO-263	A	K	A	Tape Reel

Note: Pin Assignment: A: Anode K: Cathode

<p>MBR3045CG-TA3-T</p>	<p>(1) T: Tube, R: Tape Reel (2) TA3: TO-220, TF1: TO-220F1, TF3: TO-220F, TQ2: TO-263 (3) G: Halogen Free and Lead Free, L: Lead Free</p>
------------------------	------------------------------------------------------------------------------------------------------------------------------------------------------

MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V _R	45	V
Peak Repetitive Reverse Voltage		V _{RRM}	45	V
Working Peak Reverse Voltage		V _{RWM}	45	V
Maximum PMS Reverse Voltage		V _{R(RMS)}	31.5	V
Average Rectified Forward Current (Rated V _R) T _C =130°C (Note 1)	Per Leg	I _O	15	A
	Total		30	A
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz) (T _C =125°C)		I _{FRM}	30	A
Non-Repetitive Peak Surge Current (Surge Applied At Rated Load Conditions Half Wave, Single Phase, 60Hz)		I _{FSM}	150	A
Voltage Rate of Change (Rated V _R)		dv/dt	10000	V/μs
Typical Junction Capacitance (Note 3)		C _J	450	pF
Operating Junction Temperature (Note 3)		T _J	-65 ~ +150	°C
Storage Temperature		T _{STG}	-65 ~ +150	°C

- Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
 2. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/\theta_{JA}$.
 3. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

■ THERMAL DATA

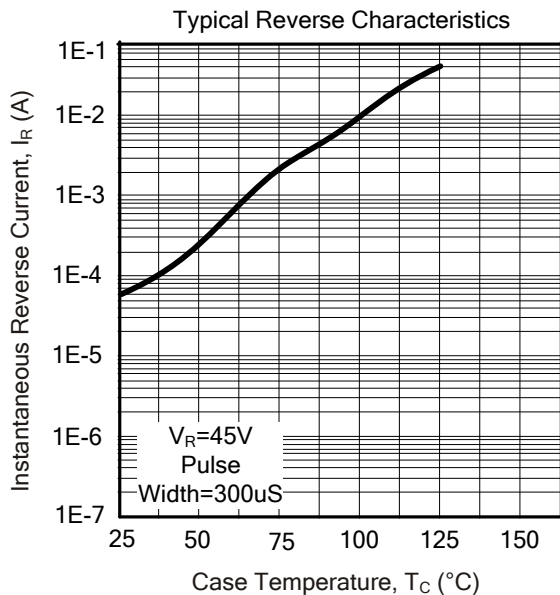
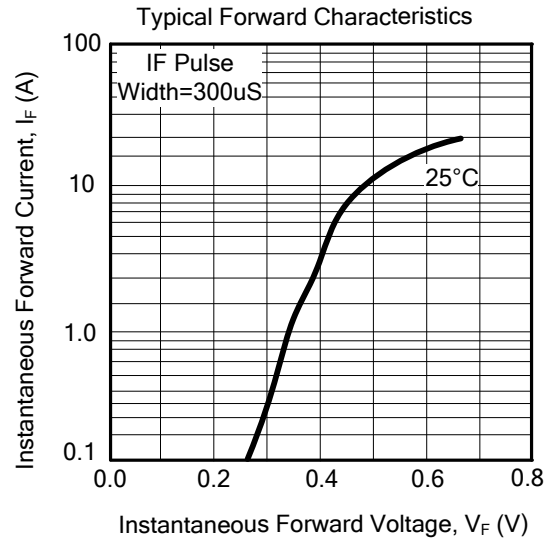
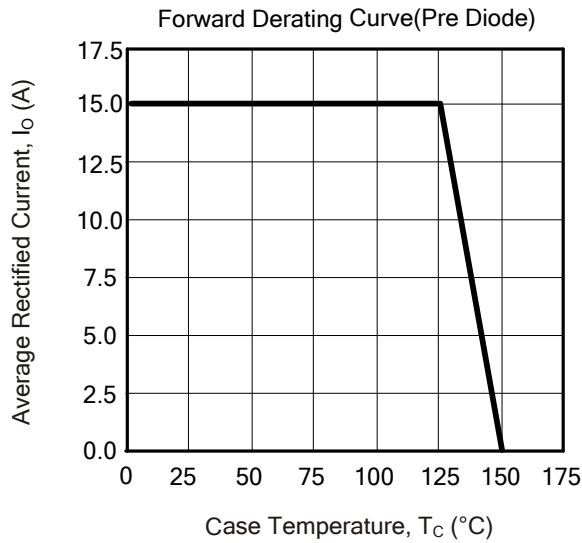
PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient		θ _{JA}	60	°C/W
Junction to Case	TO-220 TO-263	θ _{JC}	2	°C/W
	TO-220F TO-220F1		5	°C/W

■ ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Instantaneous Forward Voltage Drop	V _{FM}	I _F =15A, T _C =25°C			0.62	V
		I _F =15A, T _C =125°C			0.57	
		I _F =30A, T _C =25°C			0.76	V
		I _F =30A, T _C =125°C			0.72	
Instantaneous Reverse Current	I _{RM}	Rated DC Voltage, T _C =25°C			200	μA
		Rated DC Voltage, T _C =125°C			80	mA

Note: Pulse Test: Pulse Width = 300μs, Duty Cycle ≤ 2.0%.

■ TYPICAL CHARACTERISTICS



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.